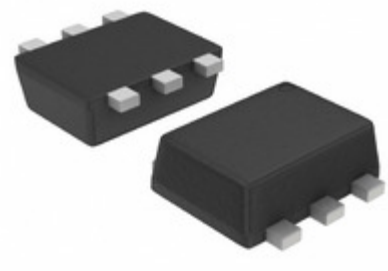









	<h2 style="color: red;">NSBA123JDXV6T5G</h2>	
	Hersteller-Teilenummer:	NSBA123JDXV6T5G
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	TRANS 2PNP PREBIAS 0.5W SOT563
Datenblätter:	 NSBA123JDXV6T5G.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 166281 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	NSBA123JDXV6T5G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS 2PNP PREBIAS 0.5W SOT563
Kategorie	Diskrete Halbleiterprodukte > Transistoren-bipolare
Teilstatus	166281 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	500mW
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SOT-563
Transistor-Typ	2 PNP - Pre-Biased (Dual)
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	250mV @ 300µA, 10mA
Strom - Collector Cutoff (Max)	500nA
DC Stromgewinn (HFE) (Min) @ Ic, VCE	80 @ 5mA, 10V
Frequenz - Übergang	-
Widerstand - Base (R1) (Ohm)	2.2k
Widerstand - Emitter-Basis (R2) (Ohm)	47k
Verpackung	Tape & Reel (TR)

NSBA123JDXV6T5G ist neu im Original, Suche NSBA123JDXV6T5G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NSBA123JDXV6T5G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NSBA123JDXV6T5G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NSBA124EDP6T5G AMI Semiconductor / ON Semiconductor TRANS 2PNP PREBIAS 0.408W SOT963</p>	 <p>NSBA124EDXV6T1 AMI Semiconductor / ON Semiconductor TRANS 2PNP PREBIAS 0.5W SOT563</p>	 <p>NSBA123JDXV6T1G AMI Semiconductor / ON Semiconductor TRANS 2PNP PREBIAS 0.5W SOT563</p>	 <p>NSBA123JDXV6T1 AMI Semiconductor / ON Semiconductor TRANS 2PNP PREBIAS 0.5W SOT563</p>
 <p>NSBA123JDXV6T5 Son NSBA123JDXV6T5 Son</p>	 <p>NSBA123JDP6T5G AMI Semiconductor / ON Semiconductor TRANS 2PNP PREBIAS 0.408W SOT963</p>	 <p>NSBA123EF3T5G AMI Semiconductor / ON Semiconductor TRANS PREBIAS DUAL PNP</p>	 <p>NSBA123JF3T5G AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 254MW SOT1123</p>

heiße Teile

Mehr

⚙️ 22255C105JAT2A	➡️ 5SNS0100W120100	➡️ ADS1120IPWR	D BTA316X-800B	➡️ CEP110P03
⚡️ DRV401AIRGWRG4	⚙️ DSA17-06A	D EXC24CG240U	➡️ LDB182G5005G-120	➡️ MP02HBT175-18
⚙️ NSB1706DMW5T1G	⚡️ NSB4904DW1T1G	⚙️ NSB8JT-E3/31	➡️ NSB9435T1	➡️ NSB9435T1G
D NSBA114EDP6T5G	⚙️ NSBA114EDXV6T1	⚡️ NSBA114YDXV6T1	⚙️ NSBA123JDXV6T1	➡️ NSBA123JDXV6T1G
➡️ NSBA143TDXV6T1G	➡️ NSBA144EDP6T5G	⚙️ NSBC114EDXV6T1	⚡️ NSBC114EDXV6T1G	➡️ NSBC114EPDXV6T1G
➡️ NSBC114EPDXV6T5	➡️ NSBC114TDXV6T1	D NSBC114YDP6T5G	⚙️ NSBC114YDXV6T1	⚡️ NSBC114YDXV6T1G
⚙️ NSBC114YDXV6T5	D NSBC114YPDXV6T1	➡️ NSBC115EDXV6T1	➡️ NSBC123JDXV6T1	➡️ NSBC123JPDXV6T1
⚡️ NSBC123JPDXV6T1G	⚙️ NSBC124EPDXV6T1	➡️ NSBC124EPDXV6T5	➡️ NSBC124XPDXV6T1	➡️ NSBC143EDXV6T5
⚙️ NSBC143ZPDXV6T1G	⚡️ NSBC143ZPDXV6T5	⚙️ NSBC144EDXV6T1	D NSBC144EDXV6T1G	➡️ NSBC144EDXV6T5
➡️ NSBC144EDXV6T5G	⚙️ NSBC144EPDXV6T1	⚡️ NSBC144EPDXV6T1G	⚙️ SFH6286-3	➡️ SKD160/08

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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